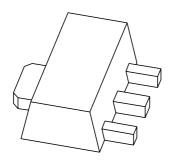
## **DISCRETE SEMICONDUCTORS**

## DATA SHEET



# BCX51; BCX52; BCX53 PNP medium power transistors

Product specification Supersedes data of 1999 Apr 19 2001 Oct 10





## **PNP** medium power transistors

BCX51; BCX52; BCX53

#### **FEATURES**

- High current (max. 1 A)
- Low voltage (max. 80 V).

## **APPLICATIONS**

- Medium power general purposes
- Driver stages of audio amplifiers.

## **DESCRIPTION**

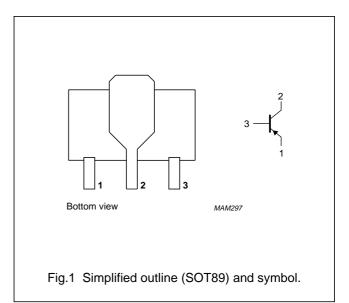
PNP medium power transistor in a SOT89 plastic package. NPN complements: BCX54, BCX55 and BCX56.

## **MARKING**

TYPE NUMBER	MARKING CODE	TYPE NUMBER	MARKING CODE
BCX51	AA	BCX52-16	AM
BCX51-10	AC	BCX53	AH
BCX51-16	AD	BCX53-10	AK
BCX52	AE	BCX53-16	AL
BCX52-10	AG		

## **PINNING**

PIN	DESCRIPTION			
1	emitter			
2	collector			
3	base			



2001 Oct 10 2

## PNP medium power transistors

BCX51; BCX52; BCX53

#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter			
	BCX51		_	-45	V
	BCX52		_	-60	V
	BCX53		_	-100	V
V <sub>CEO</sub>	collector-emitter voltage	open base			
	BCX51		_	<b>-45</b>	V
	BCX52		_	-60	V
	BCX53		_	-80	V
V <sub>EBO</sub>	emitter-base voltage	open collector	_	-5	V
I <sub>C</sub>	collector current (DC)		_	-1	Α
I <sub>CM</sub>	peak collector current		_	-1.5	Α
I <sub>BM</sub>	peak base current		_	-200	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C; note 1	_	1.3	W
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C

## Note

## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	94	K/W
R <sub>th j-s</sub>	thermal resistance from junction to soldering point	note 1	14	K/W

#### Note

1. Device mounted on a printed-circuit board, single-sided copper, tinplated, mounting pad for collector 6 cm<sup>2</sup>. For other mounting conditions, see "Thermal considerations for SOT89 in the General Part of associated Handbook".

<sup>1.</sup> Device mounted on a printed-circuit board, single-sided copper, tinplated, mounting pad for collector 6 cm<sup>2</sup>. For other mounting conditions, see "Thermal considerations for SOT89 in the General Part of associated Handbook".

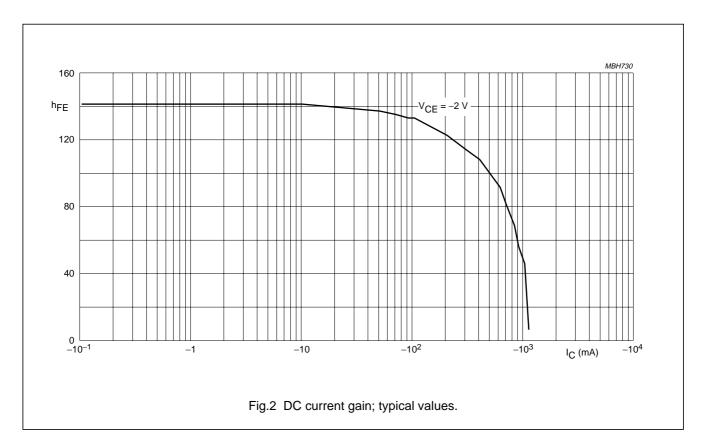
## PNP medium power transistors

BCX51; BCX52; BCX53

## **CHARACTERISTICS**

 $T_{amb}$  = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>CBO</sub>	collector cut-off current	$I_E = 0; V_{CB} = -30 \text{ V}$	_	_	-100	nA
		$I_E = 0$ ; $V_{CB} = -30 \text{ V}$ ; $T_j = 125 ^{\circ}\text{C}$	_	_	-10	μΑ
I <sub>EBO</sub>	emitter cut-off current	$I_C = 0; V_{EB} = -5 \text{ V}$	_	_	-100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = −2 V; see Fig.2				
		$I_C = -5 \text{ mA}$	63	_	_	
		$I_{C} = -150 \text{ mA}$	63	_	250	
		$I_{C} = -500 \text{ mA}$	40	_	_	
	DC current gain	$I_C = -150 \text{ mA}; V_{CE} = -2 \text{ V}; \text{ see Fig.2}$				
	BCX51-10; BCX52-10; BCX53-10		63	_	160	
	BCX51-16; BCX52-16; BCX53-16		100	_	250	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = -500 \text{ mA}; I_B = -50 \text{ mA}$	_	_	-500	mV
V <sub>BE</sub>	base-emitter voltage	$I_C = -500 \text{ mA}; V_{CE} = -2 \text{ V}$	_	_	-1	V
f <sub>T</sub>	transition frequency	$I_C = -10 \text{ mA}; V_{CE} = -5 \text{ V}; f = 100 \text{ MHz}$	_	50	_	MHz



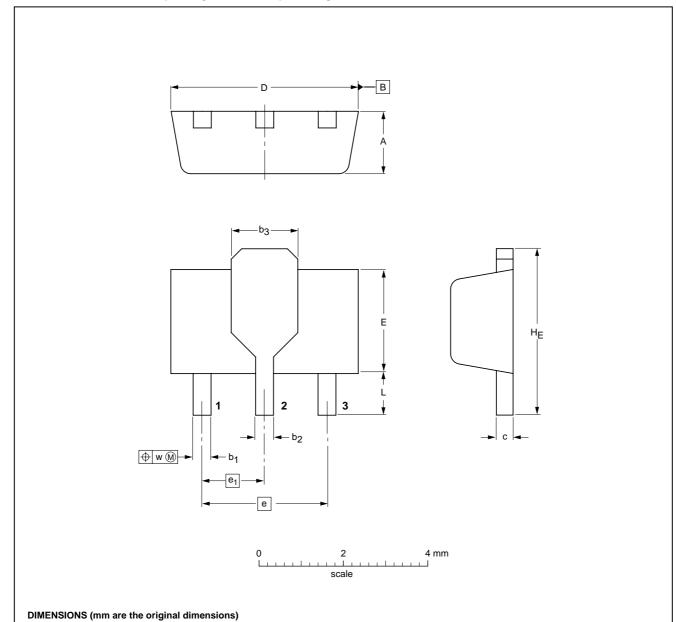
## PNP medium power transistors

BCX51; BCX52; BCX53

## **PACKAGE OUTLINE**

Plastic surface mounted package; collector pad for good heat transfer; 3 leads

**SOT89** 



UNIT	· A	b <sub>1</sub>	b <sub>2</sub>	b3	С	D	E	е	e <sub>1</sub>	HE	L min.	w
mm	1.6 1.4	0.48 0.35	0.53 0.40	1.8 1.4	0.44 0.37	4.6 4.4	2.6 2.4	3.0	1.5	4.25 3.75	0.8	0.13

OUTLINE		REFER	ENCES	EUROPEAN ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE	
SOT89		TO-243	SC-62		<del>97-02-28</del> 99-09-13	

2001 Oct 10 5

## PNP medium power transistors

BCX51; BCX52; BCX53

#### **DATA SHEET STATUS**

DATA SHEET STATUS(1)	PRODUCT STATUS <sup>(2)</sup>	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A.

#### **Notes**

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

## **DEFINITIONS**

**Short-form specification** — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information — Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors make no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

## **DISCLAIMERS**

Life support applications — These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips Semiconductors customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips Semiconductors for any damages resulting from such application.

Right to make changes — Philips Semiconductors reserves the right to make changes, without notice, in the products, including circuits, standard cells, and/or software, described or contained herein in order to improve design and/or performance. Philips Semiconductors assumes no responsibility or liability for the use of any of these products, conveys no licence or title under any patent, copyright, or mask work right to these products, and makes no representations or warranties that these products are free from patent, copyright, or mask work right infringement, unless otherwise specified.

## PNP medium power transistors

BCX51; BCX52; BCX53

**NOTES** 

## Philips Semiconductors – a worldwide company

#### **Contact information**

For additional information please visit http://www.semiconductors.philips.com. Fax: +31 40 27 24825 For sales offices addresses send e-mail to: sales.addresses@www.semiconductors.philips.com.

© Koninklijke Philips Electronics N.V. 2001

SCA73

All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner.

The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent- or other industrial or intellectual property rights.

Printed in The Netherlands

613514/04/pp8

Date of release: 2001 Oct 10

Document order number: 9397 750 08743

Let's make things better.

Philips Semiconductors



